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PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Masateru NAKAMURA

Application No.: New U.S. National Stage of PCT/JP2004/017562

Filed: January 31, 2006

Docket No.: 126868

For: METHOD OF PRODUCTION OF SILICON CARBIDE SINGLE CRYSTAL

**PRELIMINARY AMENDMENT**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

Please consider the following:

**Amendments to the Claims** as reflected in the listing of claims;

**Remarks.**